NSN 5961-01-418-5647

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.460 inches
End Application:
An/upm-155 te
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 breakdown voltage, instantaneous
Capacitance Rating In Picofarads:
0.5
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
2 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0